

RJK0351DPA

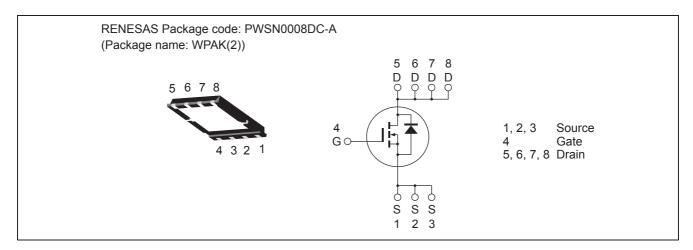
Silicon N Channel Power MOS FET Power Switching

REJ03G1646-0210 Rev.2.10 May 12, 2010

Features

- High speed switching
- Capable of 4.5 V gate drive
- Low drive current
- High density mounting
- Low on-resistance $R_{DS(on)}\!=3.2~\text{m}\Omega~\text{typ.}~(\text{at}~V_{GS}=10~\text{V})$
- Pb-free

Outline



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item	Symbol	Ratings	Unit
Drain to source voltage	V _{DSS}	30	V
Gate to source voltage	V_{GSS}	±20	V
Drain current	I _D	40	A
Drain peak current	I _{D(pulse)} Note1	160	A
Body-drain diode reverse drain current	I _{DR}	40	A
Avalanche current	I _{AP} Note 2	17	A
Avalanche energy	E _{AR} Note 2	28.9	mJ
Channel dissipation	Pch Note3	45	W
Channel to Case Thermal Resistance	θch-C	2.78	°C/W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Notes: 1. PW \leq 10 μ s, duty cycle \leq 1%

- 2. Value at Tch = 25°C, Rg \geq 50 Ω
- 3. Tc = 25°C

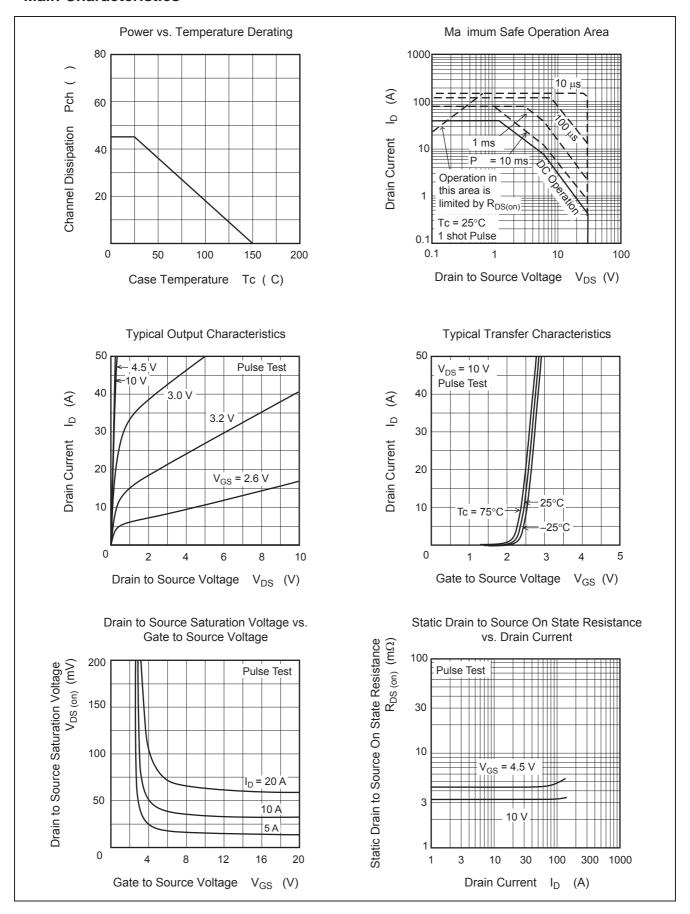
Electrical Characteristics

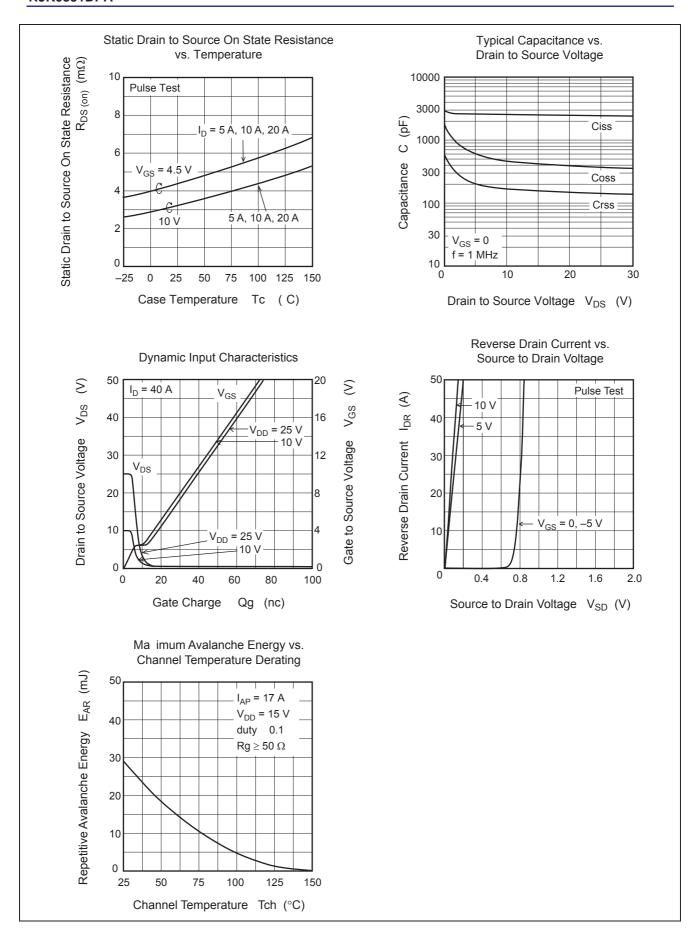
 $(Ta = 25^{\circ}C)$

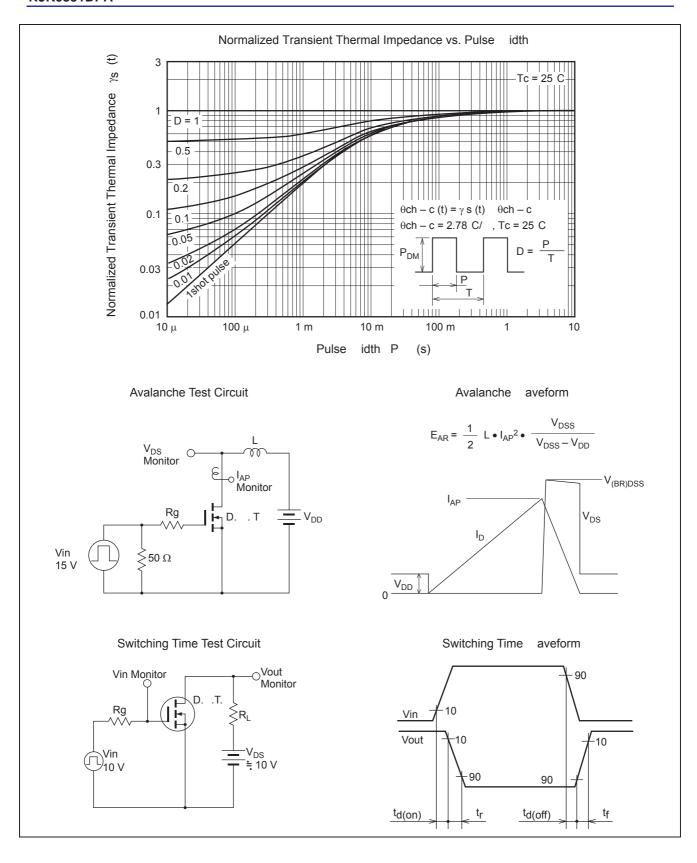
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain to source breakdown voltage	V _{(BR)DSS}	30	_	_	V	$I_D = 10 \text{ mA}, V_{GS} = 0$
Gate to source leak current	I _{GSS}	_	_	±0.1	μΑ	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0$
Zero gate voltage drain current	I _{DSS}	_	_	1	μΑ	$V_{DS} = 30 \text{ V}, V_{GS} = 0$
Gate to source cutoff voltage	$V_{GS(off)}$	1.2	_	2.5	V	$V_{DS} = 10 \text{ V}, I_{D} = 1 \text{ mA}$
Static drain to source on state	R _{DS(on)}	_	3.2	4.2	mΩ	$I_D = 20 \text{ A}, V_{GS} = 10 \text{ V}^{\text{Note4}}$
resistance	R _{DS(on)}	_	4.3	6.0	mΩ	$I_D = 20 \text{ A}, V_{GS} = 4.5 \text{ V}^{\text{Note4}}$
Forward transfer admittance	y _{fs}	_	90	_	S	$I_D = 20 \text{ A}, V_{DS} = 10 \text{ V}^{\text{Note4}}$
Input capacitance	Ciss	_	2560	_	pF	$V_{DS} = 10 \text{ V}, V_{GS} = 0,$
Output capacitance	Coss	_	470	_	pF	f = 1 MHz
Reverse transfer capacitance	Crss	_	180	_	pF	
Gate Resistance	Rg	_	2.4	_	Ω	
Total gate charge	Qg	_	17	_	nC	$V_{DD} = 10 \text{ V}, V_{GS} = 4.5 \text{ V},$
Gate to source charge	Qgs	_	6.3	_	nC	I _D = 40 A
Gate to drain charge	Qgd	_	3.7	_	nC	1
Turn-on delay time	t _{d(on)}	_	8.6	_	ns	$V_{GS} = 10 \text{ V}, I_D = 20 \text{ A},$
Rise time	t _r	_	5.0	_	ns	$V_{DD}\cong$ 10 V, R_L = 0.57 Ω ,
Turn-off delay time	$t_{d(off)}$	_	52	_	ns	$Rg = 4.7 \Omega$
Fall time	t _f	_	6.4	_	ns	1
Body-drain diode forward voltage	V_{DF}	_	0.82	1.07	V	$I_F = 40 \text{ A}, V_{GS} = 0^{\text{Note4}}$
Body–drain diode reverse recovery time	t _{rr}	_	25	_	ns	$I_F = 40 \text{ A}, V_{GS} = 0$ $di_F/dt = 100 \text{ A}/ \mu \text{s}$

Notes: 4. Pulse test

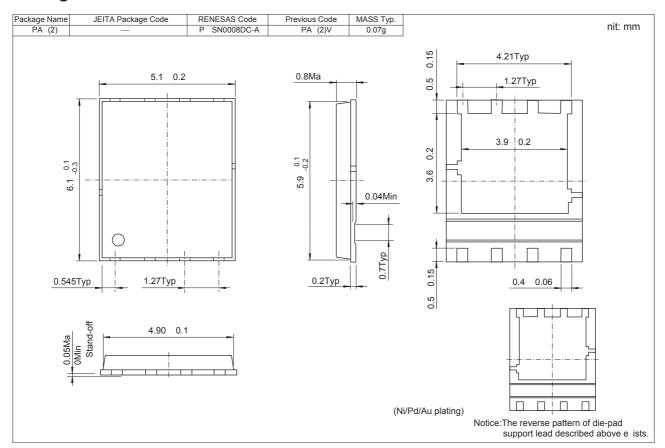
Main Characteristics







Package Dimensions



Ordering Information

Part No.	Quantity	Shipping Container
RJ 0351DPA-00-J0	2500 pcs	Taping

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